

# TA4020FT

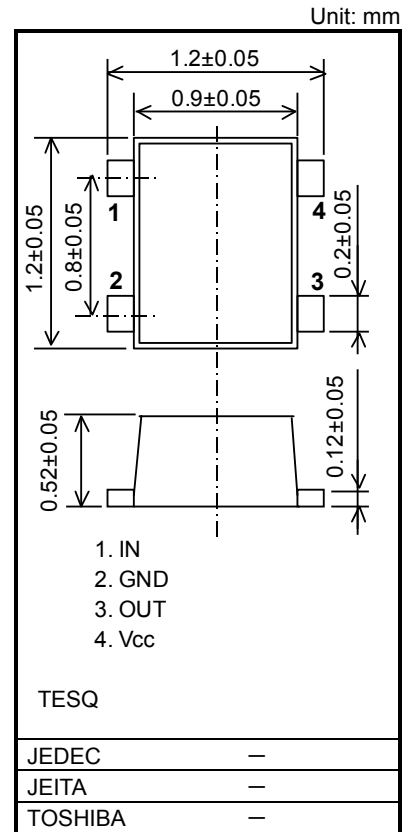
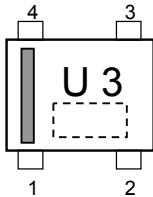
○ UHF LOW NOISE AMPLIFIER APPLICATION

- Thin Extreme Super mini Quad Package (4pin) :TESQ

## FEATURES

- Low Noise Figure: NF=0.95dB (@ f=1.5GHz)
- High Gain:  $|S_{21e}|^2=15.0\text{dB}$  (@ f=1.5GHz)
- Lead free article

## Marking(Tentative)



## Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Voltage at pin Vcc	V <sub>CC</sub>	3.7	V
Current into pin Vcc	I <sub>CC</sub>	10	mA
RF input power	P <sub>in</sub>	10	dBmW
Total Power dissipation	P <sub>D</sub>	37	mW
Junction temperature	T <sub>j</sub>	150	°C
Operate temperature Range	T <sub>opr</sub>	-40~85	°C
Storage temperature Range	T <sub>stg</sub>	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Recommend Operation range

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Voltage supply	V <sub>CC</sub>	—	2.3	3.0	3.3	V

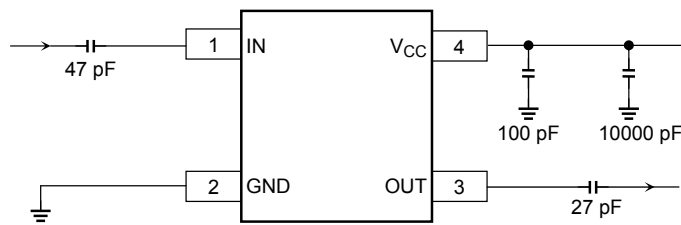
**Electrical Characteristics (Vcc = 3V, Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Circuit Current	I <sub>CC</sub>	V <sub>cc</sub> = 3V	3.5	5	7	mA
Insertion Gain	S <sub>21e</sub>   <sup>2</sup> (1)	V <sub>cc</sub> = 3V, f = 1.5GHz	13	15	—	dB
	S <sub>21e</sub>   <sup>2</sup> (2)	V <sub>cc</sub> = 3V, f = 2.6GHz	8.5	10.5	—	dB
Noise Figure	NF(1)	V <sub>cc</sub> = 3V, f = 1.5GHz, Z <sub>s</sub> = Z <sub>sopt</sub>	—	0.95	1.25	dB
	NF(2)	V <sub>cc</sub> = 3V, f = 2.6GHz, Z <sub>s</sub> = Z <sub>sopt</sub>	—	1.25	—	dB
Input Third order Intercept Point	IIP3(1)	V <sub>cc</sub> = 3V, f = 1.5GHz	—	-9.5	—	dBmW
	IIP3(2)	V <sub>cc</sub> = 3V, f = 2.6GHz	—	-4	—	dBmW

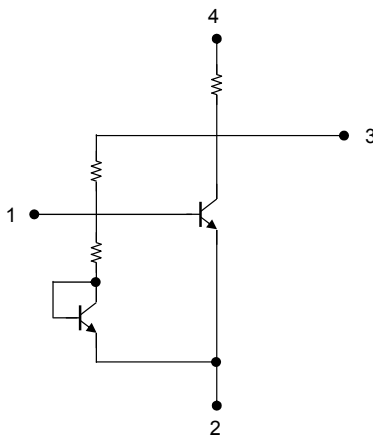
**Caution:**

This device is sensitive to electrostatic discharge due to applied the high frequency transistor process of f<sub>T</sub>=60GHz class is used for this product.

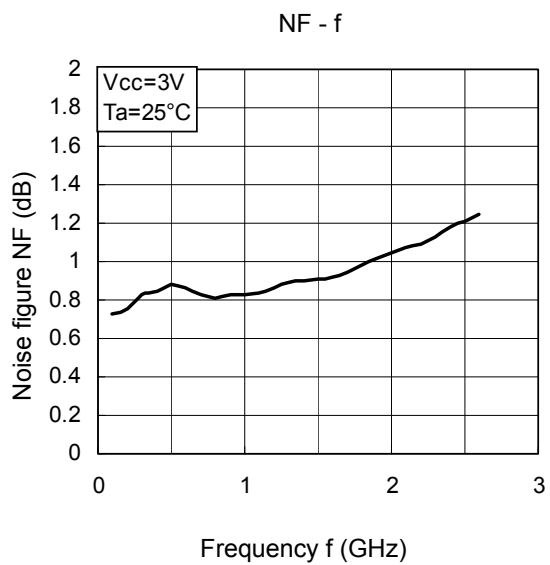
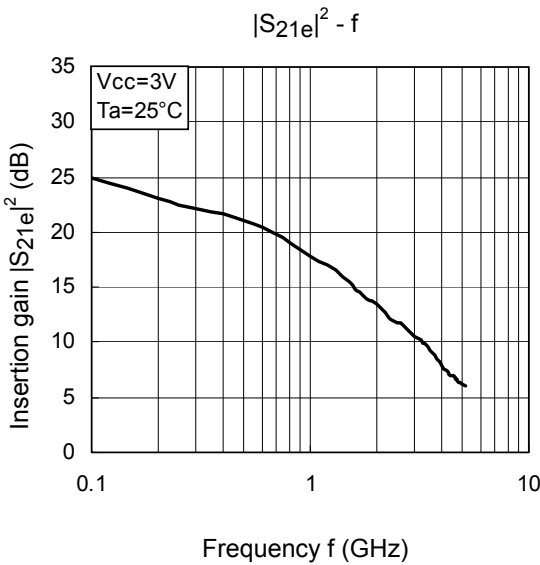
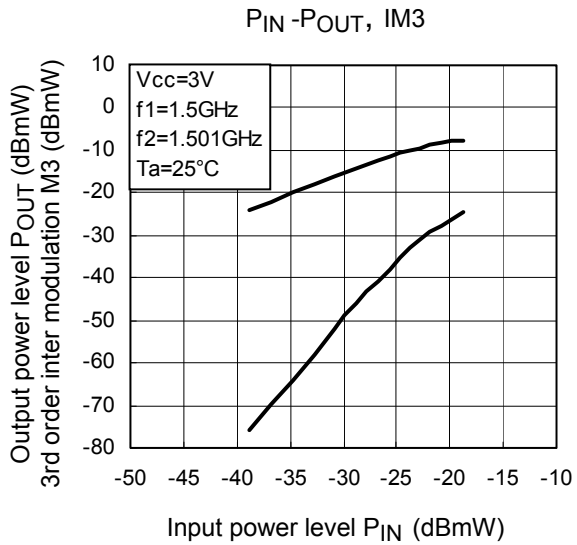
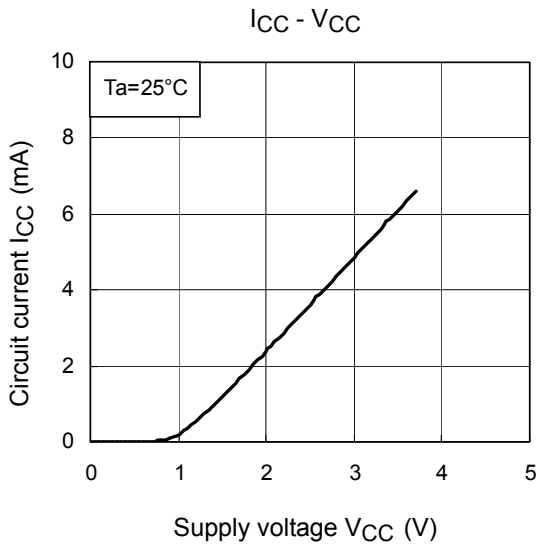
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**RF Test Circuit (Top View)**



**Equivalent Circuit**



**Notice**

The circuits and measurements contained in this document are given only in the context of as examples of applications for these products.

Moreover, these example application circuits are not intended for mass production, since the high-frequency characteristics (the AC characteristics) of these devices will be affected by the external components which the customer uses, by the design of the circuit and by various other conditions.

It is the responsibility of the customer to design external circuits which correctly implement the intended application, and to check the characteristics of the design.

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